

INFRARED DIODE LASER AT 1480nmRN-F-1480/1~500mW (TEM₀₀)**产品描述**

It features TEM₀₀ mode, ultra compact design, long lifetime, cost-effectiveness and easy operation. They are used in measurement, communication, spectrum analysis, etc

产品参数

TEM-F-1480/1~500mW (TEM ₀₀)		
Central wavelength (nm)	1480±10	
Operating mode	CW	
Output power (mW)	>1,100,200,...,500	
Power stability (rms, over 4 hours) 25°C	<1%, <2%, <3% (<0.5%, optional)	
Transverse mode	TEM ₀₀	
Ellipticity	>0.95	
M ² factor	<1.1	
Beam diameter at the aperture (1/e ² ,mm)	~1.0	
Beam divergence, full angle (mrad)	<1.5	
Warm-up time (minutes)	<5	
Beam height from base plate (mm)	25	
Operating temperature (°C)	25+/-3	
Power supply (85-264VAC)	PSU-III-LED	PSU-III-FDA
TTL / Analog modulation	TTL or Analog with 1Hz-1kHz 1kHz-10kHz, 10kHz-30kHz optional	
Expected lifetime (hours)	10000	
Warranty	1 year	